Total No. of printed pages = 3 ECE 181404 07/07/123 Roll No. of candidate BINA CHOWDHURY CENTRAL LIBRARY (GIMT & GIPS) Azara, Hatkhowapara 2023 Guwahati - 781017 B.Tech. 4th Semester End-Term Examination **Electronics and Communication Engineering** ELECTRICAL ENGINEERING MATERIALS New Regulation (w.e.f. 2017-18) & New Syllabus (w.e.f. 2018-19) Full Marks - 70 Time - Three hours The figures in the margin indicate full marks for the questions. Answer Question No. 1 and any four from the rest. 1. Answer the following:  $(10 \times 1 = 10)$ In order to obtain a high value for capacitance, the permittivity of the dielectric medium should be-(a) High (b) Low (c) Zero (d) Unity (ii) Which of the following has the negative temperature co-efficient? (a) Copper (b) Tungsten (c) Germanium Aluminium (d) (iii) What is the magnetic susceptibility of superconductor? (a) +1 (b) -1(c) 0 (d) Infinite (iv) If a diamagnetic substance is brought near the north or south pole of a bar magnet, it is: Repelled by both the poles (a) Repelled by the north pole and attracted by the south pole

Attracted by the north pole and repelled by the north pole

Turn over

Attracted by both the poles

(c)

(d)

|     | (v)    | Thermal conductivity is the rate of heat transfer   |  |            |         |                   |         |      |      |  |
|-----|--------|---|--|------------|---------|-------------------|---------|------|------|--|
|     |        | (a) Per unit area per unit thickness  |  |            |         |                   |         |      |      |  |
|     |        | (b)   | Per unit area thickness  | per unit   | tempera | ature difference  | and per | unit | wall |  |
|     |        | (c) Per unit area per unit temperature difference   |  |            |         |                   |         |      |      |  |
|     |        | (d) None of the above BINA CHOWDHURY CENTRAL LIBRARY (GIMT & GIPS)  |  |            |         |                   |         |      |      |  |
|     | (vi)   | Drift current is due to  Azara, Hatkhowapara Guwahati – 781017  |  |            |         |                   |         |      |      |  |
|     |        | (a) Applied electric field over a given distance  |  |            |         |                   |         |      |      |  |
|     |        | (b)   | Random motion  | of electro | ns      |                   |         |      |      |  |
|     |        | (c) Random motion of holes  |  |            |         |                   |         |      |      |  |
|     |        | (d) Recombination of holes and electrons  |  |            |         |                   |         |      |      |  |
|     | (vii)  | i) In an indirect bandgap semiconductor, a transition between conduction band and valance band results in               |  |            |         |                   |         |      |      |  |
|     |        | (a)   | heat   |            | (b)     | light             |         |      |      |  |
|     | 87-    | (c)   | both   |            | (d)     | none of the above | ve      |      |      |  |
|     | (viii) | ii) The proton and the neutron are about — times heavier than the electron  |  |            |         |                   |         |      |      |  |
|     |        | (a)   | 1480   |            | (b)     | 1840              |         |      |      |  |
|     |        | (c)   | 1.480  |            | (d)     | 1.840             |         |      |      |  |
|     | (ix)   | is referred for a superconductor  |  |            |         |                   |         |      |      |  |
|     |        | (a)   | Paramagnetism  | 1          | (b)     | Ferromagnetism    | n       |      |      |  |
|     |        | (c)   | Ferrimagnetism   | n          | (d)     | Diamagnetism      |         |      |      |  |
|     | (x)    | The type of impurity of Antimony for a semiconductor is —   |  |            |         |                   |         |      |      |  |
|     |        | (a)   | Monovalen  |            | (b)     | Bivalent          |         |      |      |  |
|     |        | (c)   | Trivalent  |            | (d)     | Pentavalent       |         |      |      |  |
| 2.  | (a)    | Discuss the energy bands of metals, semiconductors and insulators. (5)  |  |            |         |                   |         |      |      |  |
|     | (b)    | Differentiate the different types of crystal defects of semiconductors. (5)   |  |            |         |                   |         |      |      |  |
|     | (c)    | Explain how collision between electrons affect the conductivity of a conductor. Draw its relation with temperature. (5) |  |            |         |                   |         |      |      |  |
| 3.  | (a)    | Enumerate the types of Dielectric Polarization. Explain anyone of it. (7)   |  |            |         |                   |         |      |      |  |
|     | (b)    | Briefly explain the complex dielectric constant. (3)  |  |            |         |                   |         |      |      |  |
|     | (c)    | List causes for degradation of insulators due to its ageing. (5)  |  |            |         |                   |         |      |      |  |
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| <ul><li>(b) "Superconductors may be considered perfect diamagnets." Explain.</li><li>(c) State and derive the Curie-Weiss Law.</li></ul>   | (4)<br>(5) |
|--|------------|
| (c) State and derive the Curie-Weiss Law   |            |
| (c) State and derive the Curie-Welss Daw.  | rical      |
| 5. (a) Explain the four major assumptions within the Drude model for electronic conductivity.  | (8)        |
| (b) Estimate the mean free path and the relaxation time of electrons in confidence of the number of copper ions per unit volume is $8.47 \times 10^{22}$ ions/cm <sup>3</sup> radius of a copper ion is $10^{-10}m$ and the average speed is $1.1 \times 10^5 m/s$ . | 100        |
| 6. (a) List the differences between the intrinsic and extrinsic semiconductors.  | (5)        |
| (b) Derive the continuity equation. Give its significance.   | (7)        |
| (c) Why effective mass of hole is greater than electron?  BINA CHOWDHURY CENTRAL LIBRARY   | (3)        |
|  | (3×5=15)   |
| (a) Resistivity of semiconductors Guwahati - 781017  |            |
| (b) Polarizability   |            |
| (c) Dielectric loss  |            |
| (d) Diamagnetism.  |            |